# BCW66GLT1G, SBCW66GLT1G

# **General Purpose Transistor**

# **NPN Silicon**

#### **Features**

- S Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant



Rating	Symbol	Value	Unit
Collector-Emitter Voltage	V <sub>CEO</sub>	45	Vdc
Collector - Base Voltage	V <sub>CBO</sub>	75	Vdc
Emitter – Base Voltage	V <sub>EBO</sub>	5.0	Vdc
Collector Current – Continuous	I <sub>C</sub>	800	mAdc
Collector Current – Pulsed	Ic	1200	mAdc

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

## THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board (Note 1), T <sub>A</sub> = 25°C	P <sub>D</sub>	225	mW
Derate above 25°C		1.8	mW/°C
Thermal Resistance, Junction-to-Ambient	D	556	°C/W
Junction-to-Ambient	$R_{\theta JA}$	556	C/VV
Total Device Dissipation Alumina	$P_{D}$		
Substrate, (Note 2) T <sub>A</sub> = 25°C		300	mW
Derate above 25°C		2.4	mW/°C
Thermal Resistance,			
Junction-to-Ambient	$R_{\theta JA}$	417	°C/W
Junction and Storage Temperature	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

- 1. FR-5 =  $1.0 \times 0.75 \times 0.062$  in.
- 2. Alumina =  $0.4 \times 0.3 \times 0.024$  in 99.5% alumina.

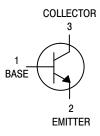


# ON Semiconductor®

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SOT-23 (TO-236) CASE 318 STYLE 6



#### **MARKING DIAGRAM**



EG = Specific Device Code M = Date Code\*

= Pb-Free Package

(\*Note: Microdot may be in either location)

\*Date Code orientation and/or overbar may vary depending upon manufacturing location.

#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
BCW66GLT1G	SOT-23 (Pb-Free)	3,000/Tape & Reel
SBCW66GLT1G	SOT-23 (Pb-Free)	3,000/Tape & Reel
BCW66GLT3G	SOT-23 (Pb-Free)	10,000/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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# **ELECTRICAL CHARACTERISTICS** (T<sub>A</sub> = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit	
OFF CHARACTERISTICS						
Collector – Emitter Breakdown Voltage (I <sub>C</sub> = 10 mAdc, I <sub>B</sub> = 0)	V <sub>(BR)CEO</sub>	45	_	_	Vdc	
Collector – Emitter Breakdown Voltage (I <sub>C</sub> = 10 μAdc, V <sub>EB</sub> = 0)	V <sub>(BR)CES</sub>	75	-	_	Vdc	
Emitter – Base Breakdown Voltage (I <sub>E</sub> = 10 μAdc, I <sub>C</sub> = 0)	V <sub>(BR)EBO</sub>	5.0	-	_	Vdc	
Collector Cutoff Current $(V_{CE} = 45 \text{ Vdc}, I_E = 0)$ $(V_{CE} = 45 \text{ Vdc}, I_E = 0, T_A = 150^{\circ}\text{C})$	ICES	_ _	_ _	20 20	nAdc μAdc	
Emitter Cutoff Current (V <sub>EB</sub> = 4.0 Vdc, I <sub>C</sub> = 0)	I <sub>EBO</sub>	_	-	20	nAdc	
ON CHARACTERISTICS						
DC Current Gain $ \begin{aligned} &(I_C = 100 \ \mu Adc, \ V_{CE} = 10 \ Vdc) \\ &(I_C = 10 \ mAdc, \ V_{CE} = 1.0 \ Vdc) \\ &(I_C = 100 \ mAdc, \ V_{CE} = 1.0 \ Vdc) \\ &(I_C = 500 \ mAdc, \ V_{CE} = 2.0 \ Vdc) \end{aligned} $	h <sub>FE</sub>	50 110 160 60	- - -	- - 400 -	-	
Collector – Emitter Saturation Voltage $(I_C = 500 \text{ mAdc}, I_B = 50 \text{ mAdc})$ $(I_C = 100 \text{ mAdc}, I_B = 10 \text{ mAdc})$	V <sub>CE(sat)</sub>		_ _	0.7 0.3	Vdc	
Base – Emitter Saturation Voltage $(I_C = 500 \text{ mAdc}, I_B = 50 \text{ mAdc})$	V <sub>BE(sat)</sub>	_	_	2.0	Vdc	
SMALL-SIGNAL CHARACTERISTICS	•		_			
Current – Gain — Bandwidth Product (I <sub>C</sub> = 20 mAdc, V <sub>CE</sub> = 10 Vdc, f = 100 MHz)	f <sub>T</sub>	100	_	_	MHz	
Output Capacitance $(V_{CB} = 10 \text{ Vdc}, I_E = 0, f = 1.0 \text{ MHz})$	C <sub>obo</sub>	-	_	12	pF	
Input Capacitance ( $V_{EB} = 0.5 \text{ Vdc}$ , $I_{C} = 0$ , $f = 1.0 \text{ MHz}$ )	C <sub>ibo</sub>	-	_	80	pF	
Noise Figure (V <sub>CE</sub> = 5.0 Vdc, I <sub>C</sub> = 0.2 mAdc, R <sub>S</sub> = 1.0 k $\Omega$ , f = 1.0 kHz, BW = 200 Hz)	NF	-	-	10	dB	
SWITCHING CHARACTERISTICS						
Turn-On Time (I <sub>B1</sub> = I <sub>B2</sub> = 15 mAdc)	t <sub>on</sub>	_	-	100	ns	
Turn–Off Time ( $I_C$ = 150 mAdc, $R_L$ = 150 $\Omega$ )	t <sub>off</sub>	_	-	400	ns	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

## **TYPICAL CHARACTERISTICS**

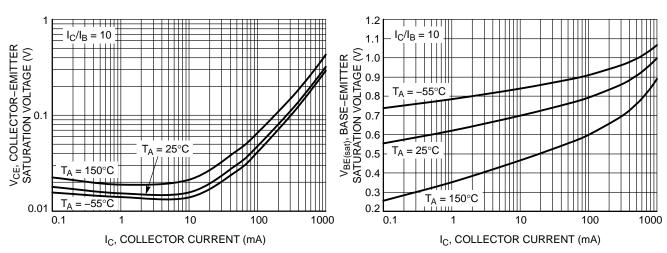


Figure 1. Collector Emitter Saturation Voltage vs. Collector Current

Figure 2. Base Emitter Saturation Voltage vs.
Collector Current

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#### **TYPICAL CHARACTERISTICS**

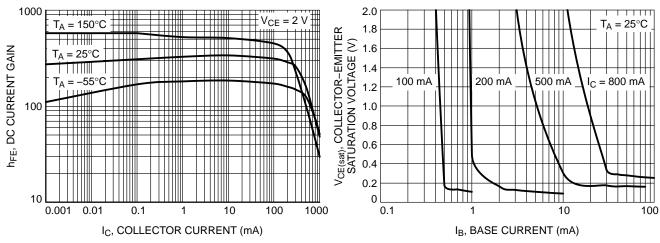


Figure 3. DC Current Gain vs. Collector Current

Figure 4. Saturation Region

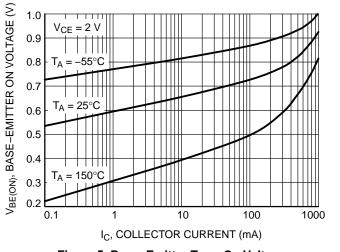


Figure 5. Base–Emitter Turn–On Voltage vs.
Collector Current

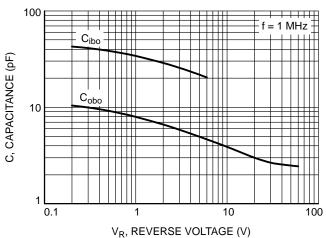


Figure 6. Capacitance

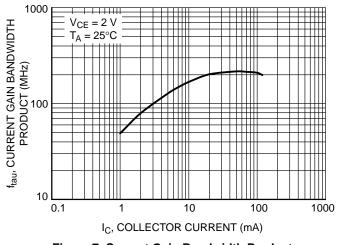


Figure 7. Current Gain Bandwidth Product vs.

Collector Current

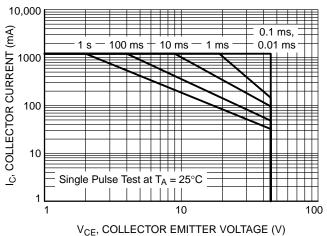
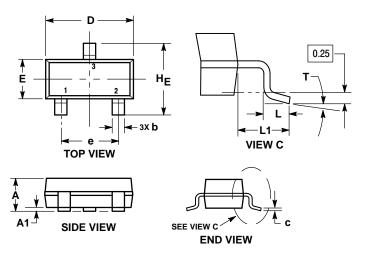


Figure 8. Safe Operating Area

## BCW66GLT1G, SBCW66GLT1G

#### PACKAGE DIMENSIONS

SOT-23 (TO-236) CASE 318-08 **ISSUE AR** 



- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994. CONTROLLING DIMENSION: MILLIMETERS. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF
- THE BASE MATERIAL.

  DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH,
  PROTRUSIONS, OR GATE BURRS.

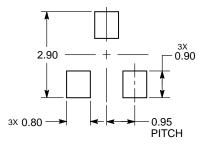
	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.89	1.00	1.11	0.035	0.039	0.044
A1	0.01	0.06	0.10	0.000	0.002	0.004
b	0.37	0.44	0.50	0.015	0.017	0.020
С	0.08	0.14	0.20	0.003	0.006	0.008
D	2.80	2.90	3.04	0.110	0.114	0.120
E	1.20	1.30	1.40	0.047	0.051	0.055
е	1.78	1.90	2.04	0.070	0.075	0.080
L	0.30	0.43	0.55	0.012	0.017	0.022
L1	0.35	0.54	0.69	0.014	0.021	0.027
HE	2.10	2.40	2.64	0.083	0.094	0.104
Т	0°		10°	0°		10°

#### STYLE 6:

PIN 1. 2. BASE

- **EMITTER**
- COLLECTOR

#### **RECOMMENDED** SOLDERING FOOTPRINT\*



**DIMENSIONS: MILLIMETERS** 

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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